Automotive P-Channel 30 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY	
V_{DS} (V)	-30
$R_{DS(on)}$ (Ω) at V_{GS} = -10 V	0.0085
$R_{DS(on)}$ (Ω) at V_{GS} = -4.5 V	0.0200
I_D (A)	-22
Configuration	Single

FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- ESD Protection: 3000 V
- 100 % UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

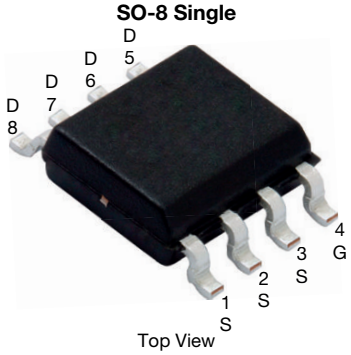
AUTOMOTIVE GRADE

Pb-free

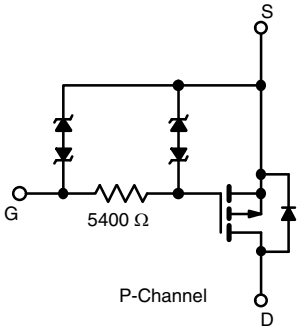
RoHS COMPLIANT

HALOGEN FREE

SO-8 Single



Top View



ORDERING INFORMATION	
Package	SO-8
Lead (Pb)-free and Halogen-free	SQ4483BEEY-T1-GE3

ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C, unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V_{DS}	-30	V
Gate-Source Voltage		V_{GS}	± 20	
Continuous Drain Current	T_C = 25 °C	I_D	-22	A
	T_C = 125 °C		-13	
Continuous Source Current (Diode Conduction)		I_S	-6	
Pulsed Drain Current [a]		I_{DM}	-84	
Single Pulse Avalanche Current	L = 10 mH	I_{AS}	-7	
Single Pulse Avalanche Energy		E_{AS}	245	mJ
Maximum Power Dissipation [a]	T_C = 25 °C	P_D	7	W
	T_C = 125 °C		2	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	-55 to +175	°C

THERMAL RESISTANCE RATINGS

PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient	PCB Mount [b]	R_{thJA}	85	°C/W
Junction-to-Foot (Drain)		R_{thJF}	21	

Notes

a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %.

b. When mounted on 1" square PCB (FR4 material).

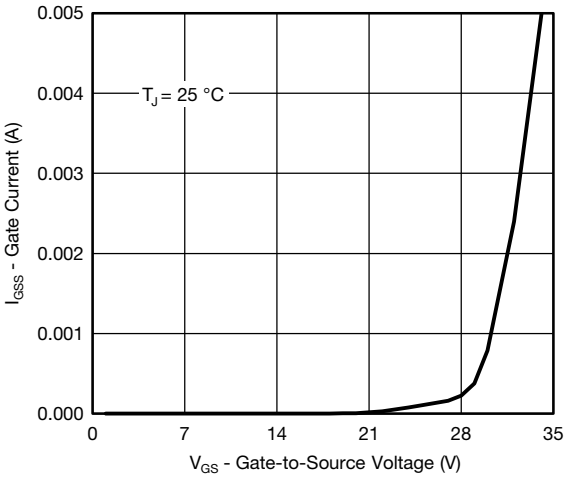
SPECIFICATIONS (T_C = 25 °C, unless otherwise noted)							
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static							
Drain-Source Breakdown Voltage	V_{DS}	V_{GS} = 0 V, I_D = -250 µA		-30	-	-	V
Gate-Source Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = -250 µA		-1.5	-2.0	-2.5	
Gate-Source Leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V		-	-	± 1	mA
		V_{DS} = 0 V, V_{GS} = ± 12 V		-	-	± 2	µA
Zero Gate Voltage Drain Current	I_{DSS}	V_{GS} = 0 V	V_{DS} = -30 V	-	-	-1	
		V_{GS} = 0 V	V_{DS} = -30 V, T_J = 125 °C	-	-	-50	
		V_{GS} = 0 V	V_{DS} = -30 V, T_J = 175 °C	-	-	-150	
On-State Drain Current [a]	$I_{D(on)}$	V_{GS} = -10 V	V_{DS} ≤ -5 V	-30	-	-	A
Drain-Source On-State Resistance [a]	$R_{DS(on)}$	V_{GS} = -10 V	I_D = -10 A	-	0.0070	0.0085	Ω
		V_{GS} = -10 V	I_D = -10 A, T_J = 125 °C	-	-	0.0130	
		V_{GS} = -10 V	I_D = -10 A, T_J = 175 °C	-	-	0.0150	
		V_{GS} = -4.5 V	I_D = -7 A	-	0.0160	0.0200	
Forward Transconductance [b]	g_{fs}	V_{DS} = -10 V, I_D = -10 A		-	32	-	S
Dynamic [b]							
Output Capacitance	C_{oss}	V_{GS} = 0 V	V_{DS} = -15 V, f = 1 MHz	-	712	890	pF
Total Gate Charge [c]	Q_g	V_{GS} = -10 V	V_{DS} = -15 V, I_D = -10 A	-	75	113	nC
Gate-Source Charge [c]	Q_{gs}			-	9.5	-	
Gate-Drain Charge [c]	Q_{gd}			-	19	-	
Turn-On Delay Time [c]	$t_{d(on)}$	V_{DD} = -15 V, R_L = 1.5 Ω I_D ≅ -10 A, V_{GEN} = -10 V, R_g = 1 Ω		-	38	57	µs
Rise Time [c]	t_r			-	82	123	
Turn-Off Delay Time [c]	$t_{d(off)}$			-	134	201	
Fall Time [c]	t_f			-	178	214	
Source-Drain Diode Ratings and Characteristics [b]							
Pulsed Current [a]	I_{SM}			-	-	-84	A
Forward Voltage	V_{SD}	I_F = -3 A, V_{GS} = 0 V		-	-0.75	-1.2	V

Notes

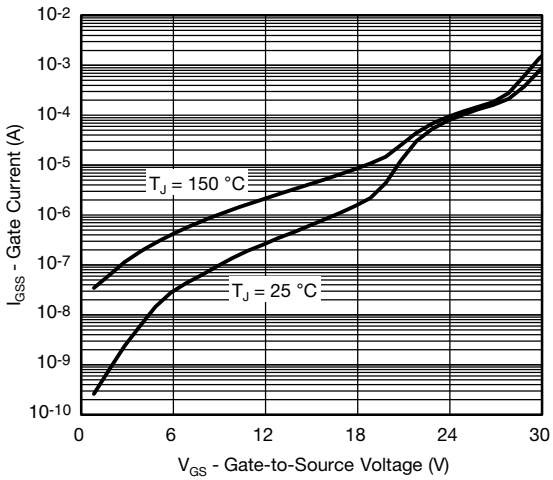
a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %.
b. Guaranteed by design, not subject to production testing.
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

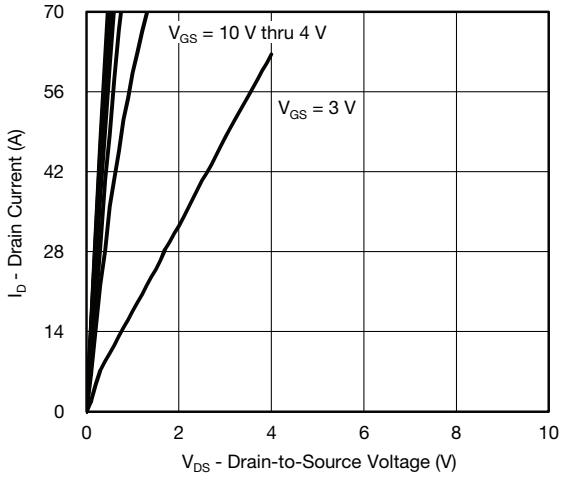
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



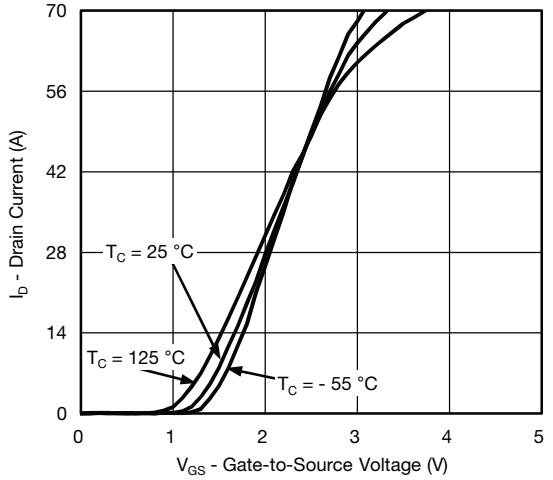
Gate Current vs. Gate-Source Voltage



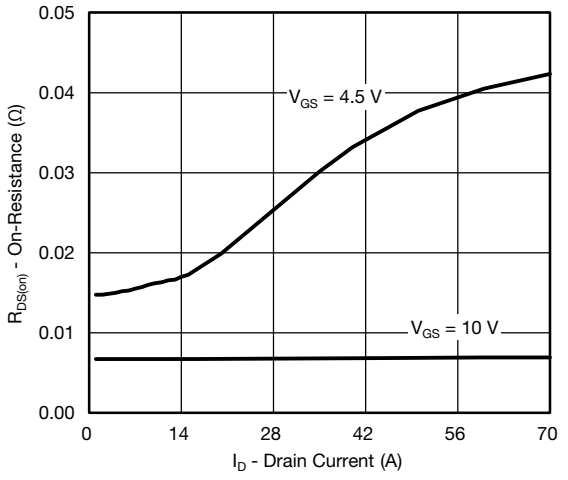
Gate Current vs. Gate-Source Voltage



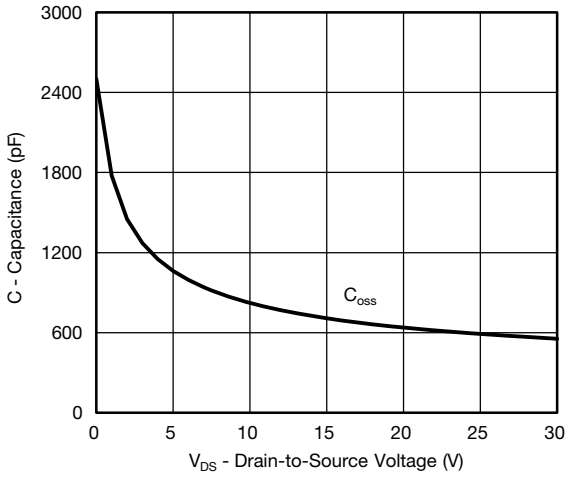
Output Characteristics



Transfer Characteristics

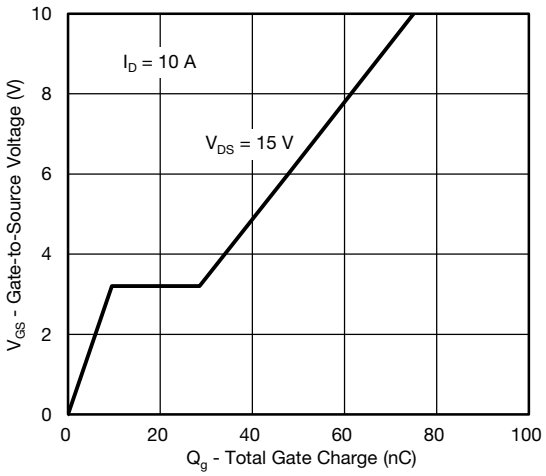


On-Resistance vs. Drain Current

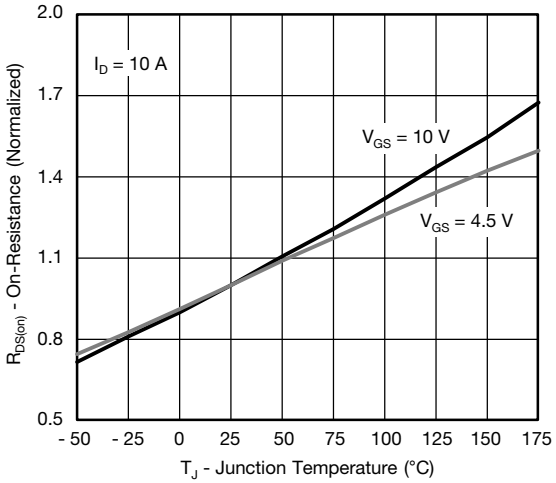


Capacitance

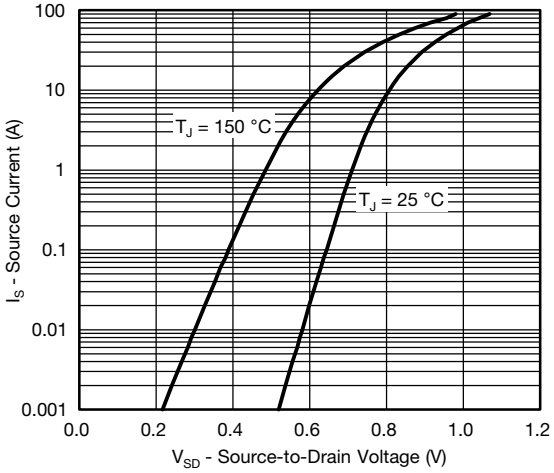
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



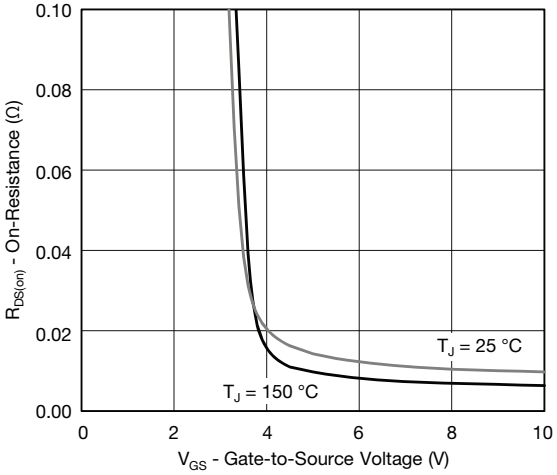
Gate Charge



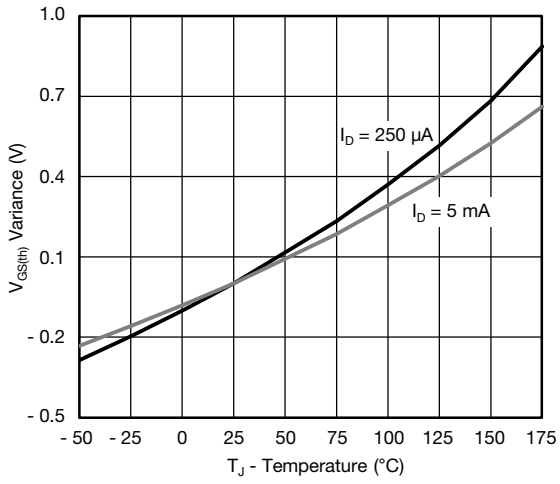
On-Resistance vs. Junction Temperature



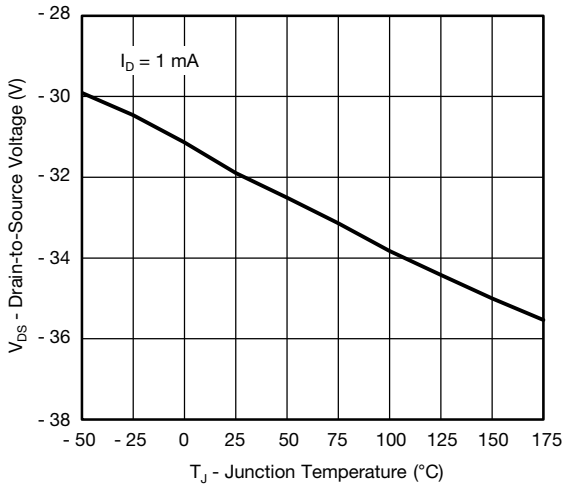
Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage

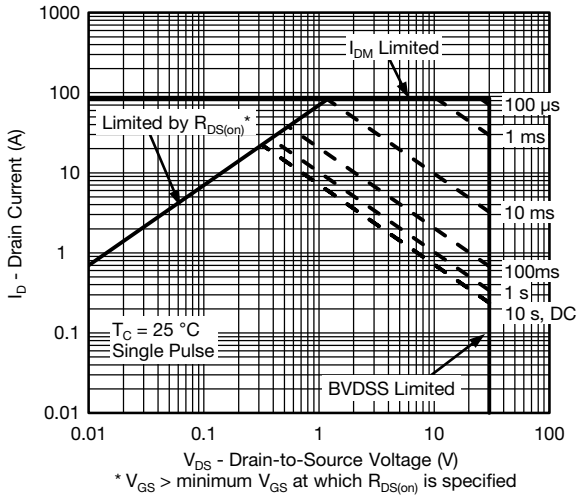


Threshold Voltage

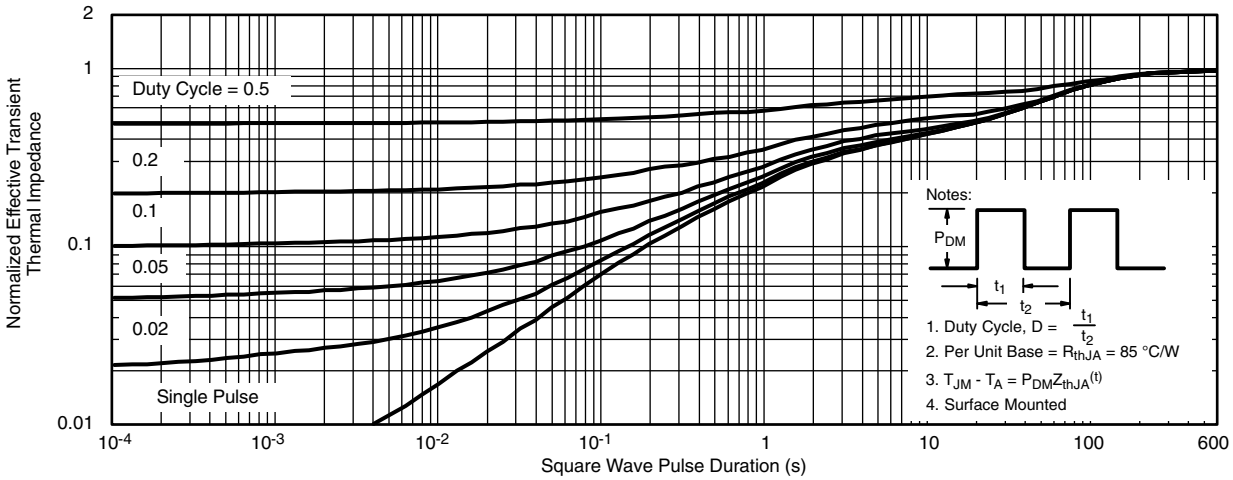


Drain Source Breakdown vs. Junction Temperature

THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)

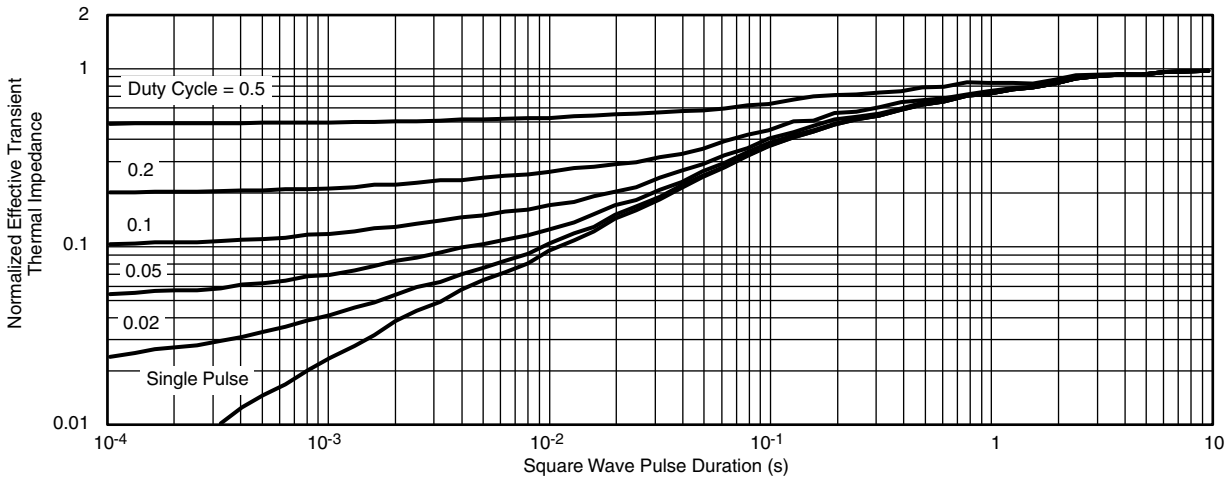


Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient

THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Foot

Note

- The characteristics shown in the two graphs
  - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
  - Normalized Transient Thermal Impedance Junction-to-Foot (25 °C)

  are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

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SO-8

Ordering codes for the SQ rugged series power MOSFETs in the SO-8 package:

DATASHEET PART NUMBER	OLD ORDERING CODE [a]	NEW ORDERING CODE
SQ4005EY	-	**SQ4005EY-T1_GE3**
SQ4050EY	SQ4050EY-T1-GE3	**SQ4050EY-T1_GE3**
SQ4182EY	SQ4182EY-T1-GE3	**SQ4182EY-T1_GE3**
SQ4184EY	SQ4184EY-T1-GE3	**SQ4184EY-T1_GE3**
SQ4282EY	SQ4282EY-T1-GE3	**SQ4282EY-T1_GE3**
SQ4284EY	SQ4284EY-T1-GE3	**SQ4284EY-T1_GE3**
SQ4401EY	SQ4401EY-T1-GE3	**SQ4401EY-T1_GE3**
SQ4410EY	SQ4410EY-T1-GE3	**SQ4410EY-T1_GE3**
SQ4425EY	SQ4425EY-T1-GE3	**SQ4425EY-T1_GE3**
SQ4431EY	SQ4431EY-T1-GE3	**SQ4431EY-T1_GE3**
SQ4435EY	SQ4435EY-T1-GE3	**SQ4435EY-T1_GE3**
SQ4470EY	SQ4470EY-T1-GE3	**SQ4470EY-T1_GE3**
SQ4483BEEY	SQ4483BEEY-T1-GE3	**SQ4483BEEY-T1_GE3**
SQ4483EY	-	**SQ4483EY-T1_GE3**
SQ4532AEY	-	**SQ4532AEY-T1_GE3**
SQ4840EY	SQ4840EY-T1-GE3	**SQ4840EY-T1_GE3**
SQ4850EY	SQ4850EY-T1-GE3	**SQ4850EY-T1_GE3**
SQ4917EY	SQ4917EY-T1-GE3	**SQ4917EY-T1_GE3**
SQ4920EY	SQ4920EY-T1-GE3	**SQ4920EY-T1_GE3**
SQ4937EY	SQ4937EY-T1-GE3	**SQ4937EY-T1_GE3**
SQ4940AEY	SQ4940AEY-T1-GE3	**SQ4940AEY-T1_GE3**
SQ4946AEY	SQ4946AEY-T1-GE3	**SQ4946AEY-T1_GE3**
SQ4949EY	SQ4949EY-T1-GE3	**SQ4949EY-T1_GE3**
SQ4961EY	SQ4961EY-T1-GE3	**SQ4961EY-T1_GE3**
SQ9407EY	SQ9407EY-T1-GE3	**SQ9407EY-T1_GE3**
SQ9945BEY	SQ9945BEY-T1-GE3	**SQ9945BEY-T1_GE3**

Note

a. Old ordering code is obsolete and no longer valid for new orders

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